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A journal on the chemical, electronic, optical and mechanical properties of glasses, amorphous semiconductors and metals, sol–gel materials, the liquid state of these solids and the processes by which they are formed

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JNCSBJ MASTER INDEX VOLS. 201–220
ISSN 0022-3093

http://www.elsevier.nl

NORTH-HOLLAND

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Aims and Scope

The Journal of Non-Crystalline Solids publishes original research papers about oxide and non-oxide glasses, amorphous semiconductors, amorphous metals, glassy and amorphous films and coatings, glass-ceramics, glass composites, and processes by which these materials are produced. Papers about the liquid state are included insofar as the properties of the liquids are relevant to the formation of non-crystalline solids.

Review papers are published occasionally. These may be solicited by the Editor or contributed. If contributed, a justification for the review and an outline of the paper should be sent to the Editor for preliminary review.

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Abstracted/indexed in:

Ceramic Abstracts; Current Contents: Physical, Chemical and Earth Sciences; EI Compendex Plus; Engineering Index; INSPEC; Materials Information.

Subscription Information 1997

Volumes 208–224 of Journal of Non-Crystalline Solids (ISSN 0022-3093) are scheduled for publication. (Frequency: monthly.) Prices are available from the publishers upon request. Subscriptions are accepted on a prepaid basis only and are entered on a calendar-year basis. Issues are sent by SAL (surface air lifted) mail wherever this service is available. Airmail rates are available upon request. For orders, claims, product enquiries (no manuscript enquiries) please contact the Customer Support Department at the Regional Sales Office nearest to you:

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US Mailing notice – Journal of Non-Crystalline Solids (ISSN 0022-3093) is published monthly, except semimonthly in February, April, May, June, July, August, September, October, November and December, by Elsevier Science B.V., Molenwerf 1, P.O. Box 211, 1000 AE Amsterdam, The Netherlands. Annual subscription price in the USA is US$ 5341 (valid in North, Central and South America only), including air speed delivery. Second class postage paid at Jamaica, NY 11431.

USA Postmasters: Send changes to Journal of Non-Crystalline Solids, Publications Expediting, Inc., 200 Meacham Avenue, Elmont, NY 11003. Airfreight and mailing in the USA by Publications Expediting.

∞ The paper used in this publication meets the requirements of ANSI/NISO Z39.48-1992 (Permanence of Paper).

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MASTER INDEX VOLS. 201–220
1996–1997

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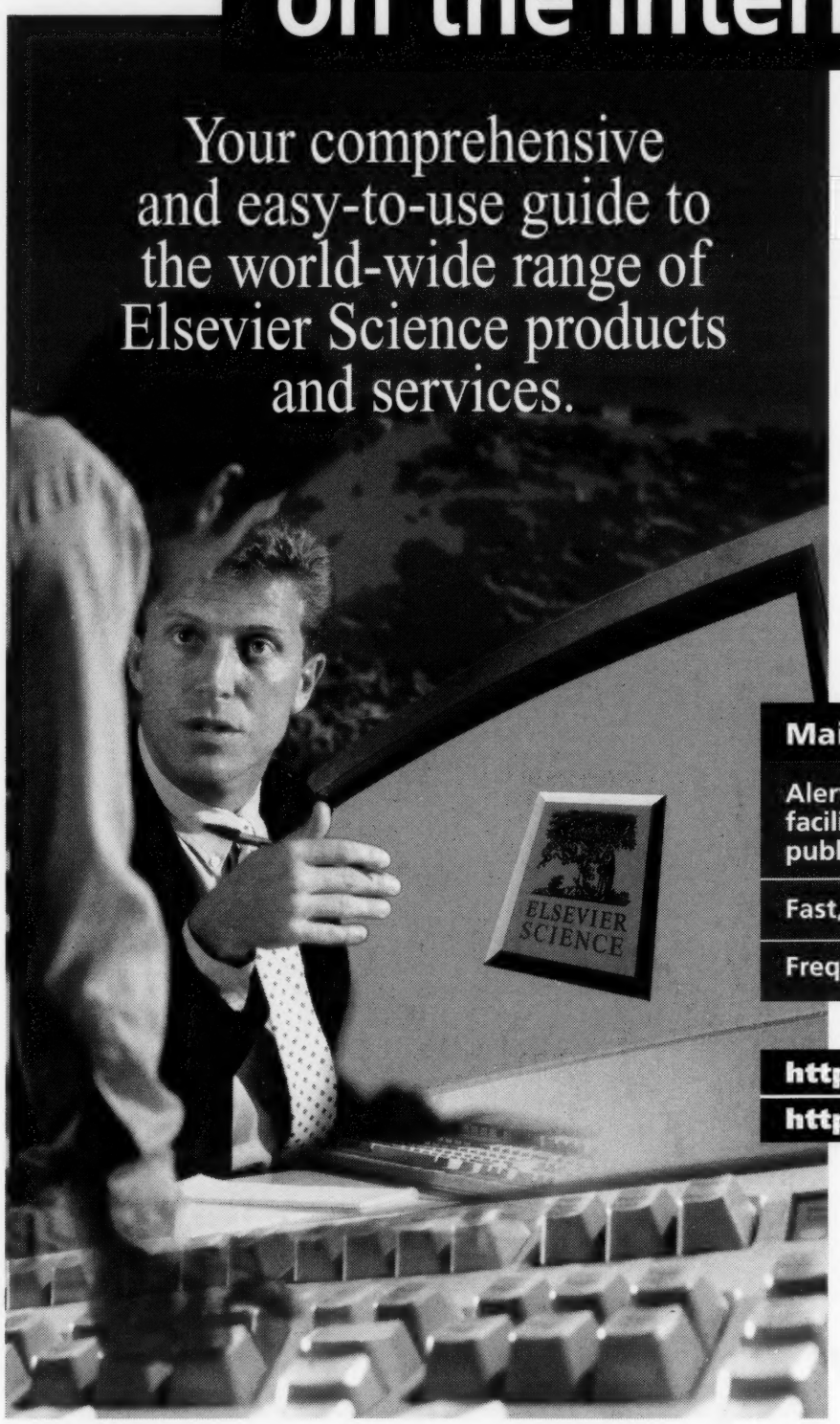

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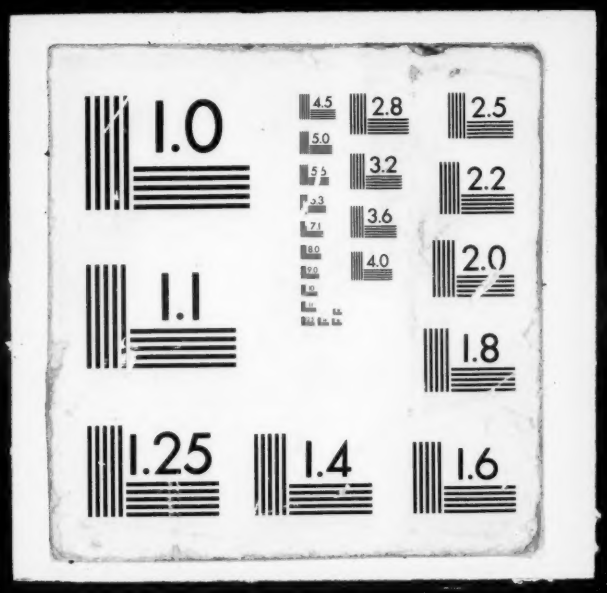
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